NSN 5961-01-310-5742

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-310-5742 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.544 inches and 0.562 inches Thread Size: 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 4.00 milliamperes base current, instantaneous preset and 80.00 milliamperes forward current, total rms preset **Special Features:** Selected for gate current; junction pattern arrangement: pnpn **Test Data Document:** 53711-6288872 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: